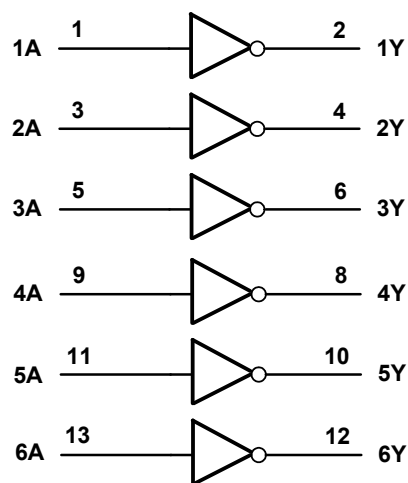


## Pin Descriptions

Pin Number	Pin Name	Function
1	1A	Data Input
2	1Y	Data Output
3	2A	Data Input
4	2Y	Data Output
5	3A	Data Input
6	3Y	Data Output
7	GND	Ground
8	4Y	Data Output
9	4A	Data Input
10	5Y	Data Output
11	5A	Data Input
12	6Y	Data Output
13	6A	Data Input
14	V <sub>CC</sub>	Supply Voltage

## Logic Diagram



## Function Table

Input	Output
A	Y
L	H
H	L

## Absolute Maximum Ratings (Note 4) (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Symbol	Description	Rating	Unit
ESD HBM	Human Body Model ESD Protection	2	KV
ESD CDM	Charged Device Model ESD Protection	1	KV
ESD MM	Machine Model ESD Protection	200	V
V <sub>CC</sub>	Supply Voltage Range	-0.5 to +7.0	V
V <sub>I</sub>	Input Voltage Range	-0.5 to +7.0	V
I <sub>IK</sub>	Input Clamp Current V <sub>I</sub> < -0.5V	-20	mA
I <sub>OK</sub>	Output Clamp Current V <sub>O</sub> < -0.5V	-20	mA
I <sub>OK</sub>	Output Clamp Current V <sub>O</sub> > V <sub>CC</sub> +0.5V	25	mA
I <sub>O</sub>	Continuous Output Current -0.5V < V <sub>O</sub> < V <sub>CC</sub> +0.5V	+/- 25	mA
I <sub>CC</sub>	Continuous Current Through V <sub>CC</sub>	75	mA
I <sub>GND</sub>	Continuous Current Through GND	-75	mA
T <sub>J</sub>	Operating Junction Temperature	-40 to +150	°C
T <sub>STG</sub>	Storage Temperature	-65 to +150	°C
P <sub>TOT</sub>	Total Power Dissipation	500	mW

Note: 4. Stresses beyond the absolute maximum may result in immediate failure or reduced reliability. These are stress values and device operation should be within recommend values.

## Recommended Operating Conditions (Note 5) (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Symbol	Parameter	Conditions	Min	Max	Unit
V <sub>CC</sub>	Supply Voltage		2.0	5.5	V
V <sub>I</sub>	Input Voltage		0	5.5	V
V <sub>O</sub>	Output Voltage		0	V <sub>CC</sub>	V
Δt/ΔV	Input Transition Rise or Fall Rate	V <sub>CC</sub> = 3.0V to 3.6V		100	ns/V
		V <sub>CC</sub> = 4.5V to 5.5V		20	
T <sub>A</sub>	Operating Free-Air Temperature		-40	+125	°C

Note: 5. Unused inputs should be held at V<sub>CC</sub> or Ground.

## Electrical Characteristics (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Symbol	Parameter	Test Conditions	V <sub>CC</sub>	T <sub>A</sub> = -40°C to +85°C		T <sub>A</sub> = -40°C to +125°C		Unit
				Min	Max	Min	Max	
V <sub>IH</sub>	High-Level Input Voltage		2.0V	1.7		1.7		V
			3.0V	2.4		2.4		
			5.5V	4.4		4.4		
V <sub>IL</sub>	Low-Level input Voltage		2.0V		0.3		0.3	V
			3.0 V		0.6		0.6	
			5.5V		1.1		1.1	
V <sub>OH</sub>	High-Level Output Voltage	I <sub>OH</sub> = -50μA	2.0V	1.8		1.8		V
		I <sub>OH</sub> = -50μA	3.0V	2.7		2.7		
		I <sub>OH</sub> = -50μA	4.5V	4.0		4.0		
		I <sub>OH</sub> = -4mA	3.0V	2.48		2.40		
		I <sub>OH</sub> = -8mA	4.5V	3.80		3.70		
V <sub>OL</sub>	Low-Level Output Voltage	I <sub>OL</sub> = 50μA	2.0V		0.2		0.2	V
		I <sub>OL</sub> = 50μA	3.0V		0.3		0.3	
		I <sub>OL</sub> = 50μA	4.5V		0.5		0.5	
		I <sub>OL</sub> = 4mA	3.0V		0.44		0.55	
		I <sub>OL</sub> = 8mA	4.5V		0.44		0.55	
I <sub>I</sub>	Input Current	V <sub>I</sub> = GND to 5.5V	3.6V		±1		±2	μA
I <sub>CC</sub>	Supply Current	V <sub>I</sub> = GND or V <sub>CC</sub> , I <sub>O</sub> = 0	3.6V		20		40	μA

## Operating Characteristics

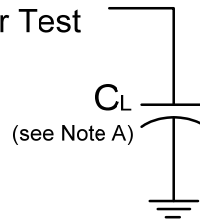
Parameter		Test Conditions	V <sub>CC</sub> = 2.0V	V <sub>CC</sub> = 3.3V	V <sub>CC</sub> = 5V	Unit
			Typ	Typ	Typ	
C <sub>pd</sub>	Power Dissipation Capacitance per Gate	f = 1MHz	7.9	8.3	9.1	pF
C <sub>i</sub>	Input Capacitance	V <sub>i</sub> = V <sub>CC</sub> – or GND	4.0	4.0	4.0	pF

## Switching Characteristics

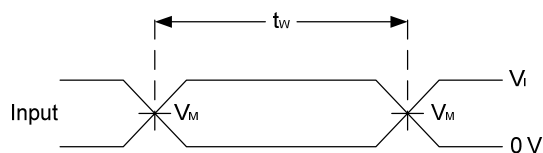
Symbol	Parameter	Test Conditions	V <sub>CC</sub>	T <sub>A</sub> = +25°C			-40°C to +85°C		-40°C to +125°C		Unit
				Min	Typ	Max	Min	Max	Min	Max	
t <sub>PD</sub>	Propagation Delay A <sub>N</sub> to Y <sub>N</sub>	Figure 1 C <sub>L</sub> = 15pF	3.0V to 3.6V	0.5	3.0	7.1	0.5	8.0	0.5	9.0	ns
			4.5V to 5.5V	0.5	2.4	5.5	0.5	6.5	0.5	7.0	
		Figure 1 C <sub>L</sub> = 50pF	3.0V to 3.6V	0.5	3.4	10.6	0.5	12.0	0.5	13.5	
			4.5V to 5.5V	0.5	3.5	7.0	0.5	8.0	0.5	9.0	

## Parameter Measurement Information

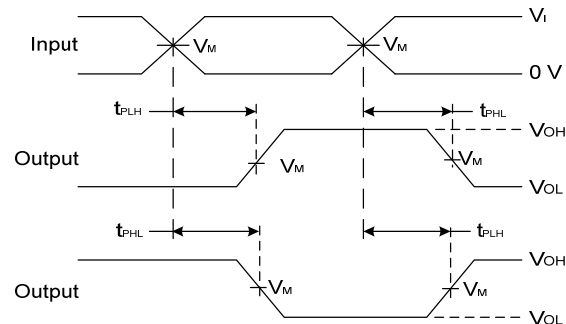
From Output  
Under Test



V <sub>CC</sub>	Inputs		V <sub>M</sub>	C <sub>L</sub>
	V <sub>I</sub>	t <sub>r</sub> /t <sub>f</sub>		
3.3V to 3.6V	V <sub>CC</sub>	3ns	V <sub>CC</sub> /2	15pF, 50pF
4.5V to 5.5V	V <sub>CC</sub>	3ns	V <sub>CC</sub> /2	15pF, 50pF



**Voltage Waveform  
Pulse Duration**

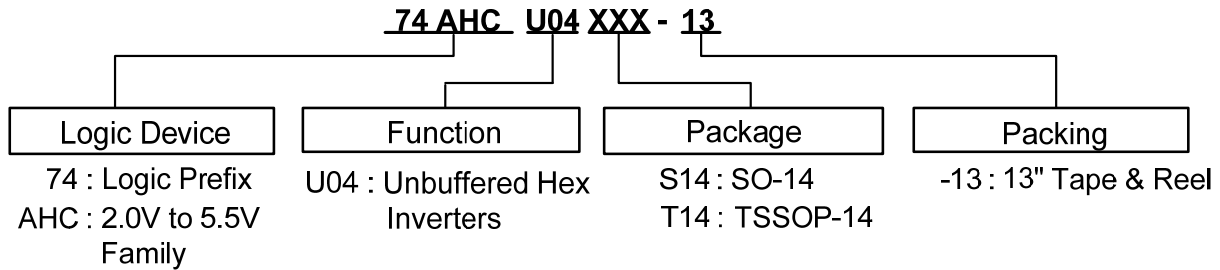


**Voltage Waveform  
Propagation Delay Times  
Inverting and Non Inverting Outputs**

**Figure 1 Load Circuit and Voltage Waveforms**

- Notes:
- A. Includes test lead and test apparatus capacitance.
  - B. All pulses are supplied at pulse repetition rate ≤ 1 MHz.
  - C. Inputs are measured separately one transition per measurement.
  - D. t<sub>PLH</sub> and t<sub>PHL</sub> are the same as t<sub>PD</sub>.

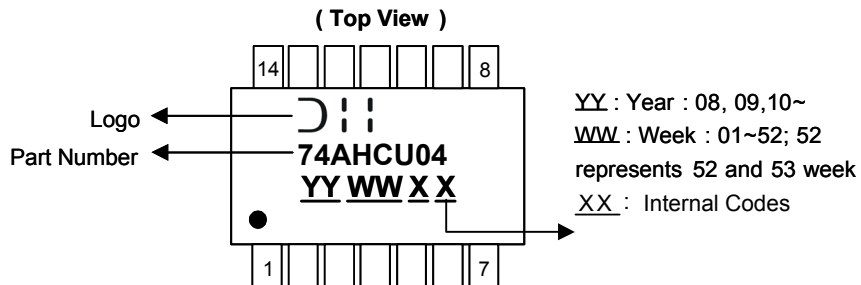
## Ordering Information



Part Number	Package Code	Packaging	7" Tape and Reel	
			Quantity	Part Number Suffix
74AHCU04S14-13	S14	SO-14	2500/Tape & Reel	-13
74AHCU04T14-13	T14	TSSOP-14	2500/Tape & Reel	-13

## Marking Information

(1) SO-14, TSSOP-14

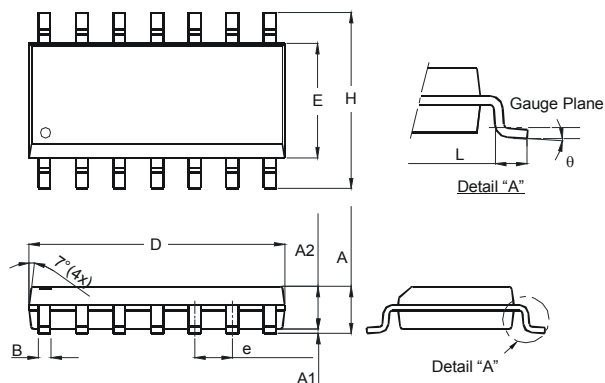


Part Number	Package
74AHCU04S14	SO-14
74AHCU04T14	TSSOP-14

## Package Outline Dimensions (All dimensions in mm.)

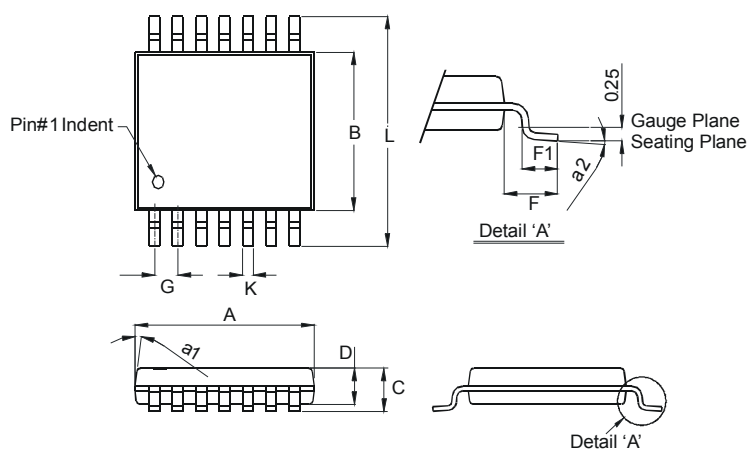
Please see AP02002 at <http://www.diodes.com/datasheets/ap02002.pdf> for latest version.

### Package Type: SO-14



SO-14		
Dim	Min	Max
A	1.47	1.73
A1	0.10	0.25
A2	1.45 Typ	
B	0.33	0.51
D	8.53	8.74
E	3.80	3.99
e	1.27 Typ	
H	5.80	6.20
L	0.38	1.27
θ	0°	8°
All Dimensions in mm		

### Package Type: TSSOP-14

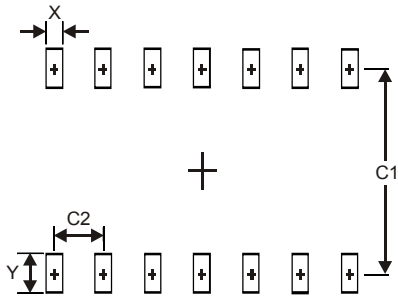


TSSOP-14		
Dim	Min	Max
a1	7° (4X)	
a2	0°	8°
A	4.9	5.10
B	4.30	4.50
C	—	1.2
D	0.8	1.05
F	1.00 Typ	
F1	0.45	0.75
G	0.65 Typ	
K	0.19	0.30
L	6.40 Typ	
All Dimensions in mm		

## Suggested Pad Layout

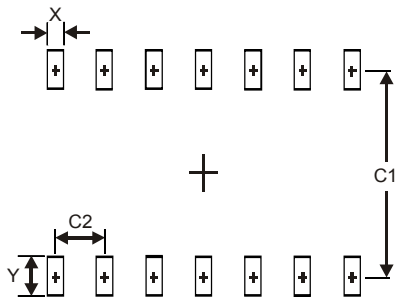
Please see AP02001 at <http://www.diodes.com/datasheets/ap02001.pdf> for the latest version.

### Package Type: SO-14



Dimensions	Value (in mm)
X	0.60
Y	1.50
C1	5.4
C2	1.27

### Package Type: TSSOP-14



Dimensions	Value (in mm)
X	0.45
Y	1.45
C1	5.9
C2	0.65

**IMPORTANT NOTICE**

DIODES INCORPORATED MAKES NO WARRANTY OF ANY KIND, EXPRESS OR IMPLIED, WITH REGARDS TO THIS DOCUMENT, INCLUDING, BUT NOT LIMITED TO, THE IMPLIED WARRANTIES OF MERCHANTABILITY AND FITNESS FOR A PARTICULAR PURPOSE (AND THEIR EQUIVALENTS UNDER THE LAWS OF ANY JURISDICTION).

Diodes Incorporated and its subsidiaries reserve the right to make modifications, enhancements, improvements, corrections or other changes without further notice to this document and any product described herein. Diodes Incorporated does not assume any liability arising out of the application or use of this document or any product described herein; neither does Diodes Incorporated convey any license under its patent or trademark rights, nor the rights of others. Any Customer or user of this document or products described herein in such applications shall assume all risks of such use and will agree to hold Diodes Incorporated and all the companies whose products are represented on Diodes Incorporated website, harmless against all damages.

Diodes Incorporated does not warrant or accept any liability whatsoever in respect of any products purchased through unauthorized sales channel.

Should Customers purchase or use Diodes Incorporated products for any unintended or unauthorized application, Customers shall indemnify and hold Diodes Incorporated and its representatives harmless against all claims, damages, expenses, and attorney fees arising out of, directly or indirectly, any claim of personal injury or death associated with such unintended or unauthorized application.

Products described herein may be covered by one or more United States, international or foreign patents pending. Product names and markings noted herein may also be covered by one or more United States, international or foreign trademarks.

This document is written in English but may be translated into multiple languages for reference. Only the English version of this document is the final and determinative format released by Diodes Incorporated.

**LIFE SUPPORT**

Diodes Incorporated products are specifically not authorized for use as critical components in life support devices or systems without the express written approval of the Chief Executive Officer of Diodes Incorporated. As used herein:

A. Life support devices or systems are devices or systems which:

1. are intended to implant into the body, or
2. support or sustain life and whose failure to perform when properly used in accordance with instructions for use provided in the labeling can be reasonably expected to result in significant injury to the user.

B. A critical component is any component in a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or to affect its safety or effectiveness.

Customers represent that they have all necessary expertise in the safety and regulatory ramifications of their life support devices or systems, and acknowledge and agree that they are solely responsible for all legal, regulatory and safety-related requirements concerning their products and any use of Diodes Incorporated products in such safety-critical, life support devices or systems, notwithstanding any devices- or systems-related information or support that may be provided by Diodes Incorporated. Further, Customers must fully indemnify Diodes Incorporated and its representatives against any damages arising out of the use of Diodes Incorporated products in such safety-critical, life support devices or systems.

Copyright © 2013, Diodes Incorporated

[www.diodes.com](http://www.diodes.com)